NSN 5962-01-415-9725

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View Online at https://aerobasegroup.com/psp/5062-01-415-0725

view Online at https://aerobasegroup.com/nsr//5962-01-415-9725
Body Length:
Between 0.540 inches and 0.560 inches
Body Width:
Between 0.442 inches and 0.458 inches
Body Height:
Between 0.060 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
B-2 bomber, instrument support equipment
Features Provided:
Electrostatic sensitive and low power and static operation and bidirectional and high impedance
Inclosure Material:
Ceramic
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Feat
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Ram
Special Features:
Nuclear hardness critical item
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
32 leadless
Shelf Life:
N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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